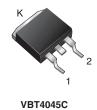


Vishay General Semiconductor

Dual Low-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.28 \text{ V}$ at $I_F = 5.0 \text{ A}$





HEATSINK

DESIGN SUPPORT TOOLS

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PRIMARY CHARACTERISTICS				
I _{F(AV)}	2 x 20 A			
V_{RRM}	45 V			
I _{FSM}	240 A			
V _F at I _F = 20 A	0.41 V			
T _J max.	150 °C			
Package	D ² PAK (TO-263AB)			
Circuit configuration	ation Common cathode			

FEATURES

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses



RoHS COMPLIANT HALOGEN

FREE

- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

MECHANICAL DATA

Case: D²PAK (TO-263AB)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	VBT4045C	UNIT	
Maximum repetitive peak reverse voltage		V _{RRM}	45	V	
Maximum average forward rectified current (fig. 1)	per device		40	^	
	per diode	I _{F(AV)}	20	A	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load		I _{FSM}	240	А	
Operating junction and storage temperature range		T _J , T _{STG}	-40 to +150	°C	



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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	I _F = 5 A	T _A = 25 °C	V _F ⁽¹⁾	0.41	-	. V	
	$I_F = 10 A$			0.44	-		
	I _F = 20 A			0.50	0.58		
	I _F = 5 A	T _A = 125 °C		0.28	-		
	I _F = 10 A			0.33	-		
	I _F = 20 A			0.41	0.50		
Reverse current per diode	V _R = 45 V	T _A = 25 °C	I _R ⁽²⁾	-	3000	μA	
	v _R = 45 v	T _A = 125 °C		18	50	mA	

Notes

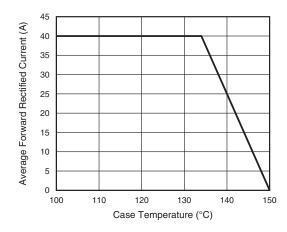
(1) Pulse test: 300 μs pulse width, 1 % duty cycle

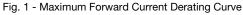
(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	VBT4045C	UNIT	
Typical thermal resistance	per diode	$R_{ hetaJC}$	1.5	°C/W	
	per device		0.8	- C/VV	

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-263AB	VBT4045C-M3/4W	1.38	4W	50/tube	Tube		
TO-263AB	VBT4045C-M3/8W	1.38	8W	800/reel	Tape and reel		

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)





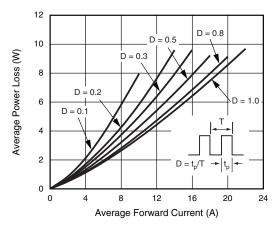


Fig. 2 - Forward Power Loss Characteristics Per Diode



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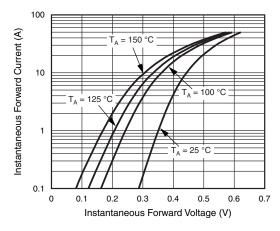


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

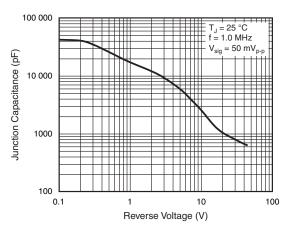


Fig. 5 - Typical Junction Capacitance Per Diode

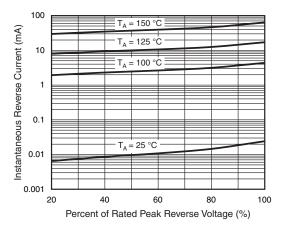


Fig. 4 - Typical Reverse Characteristics Per Diode

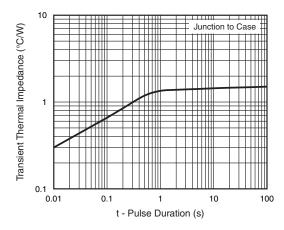
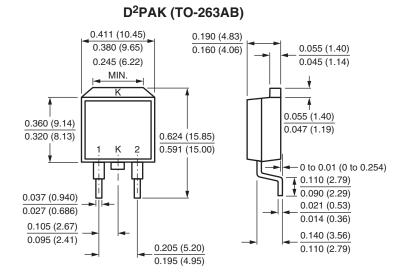
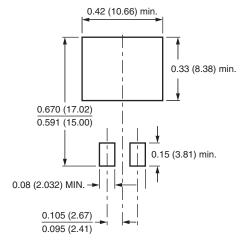


Fig. 6 - Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



Mounting Pad Layout





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